

- Max $r_{DS(on)} = 5.0 \text{ m}\Omega \text{ at } V_{GS} = 10 \text{ V}, I_D = 18 \text{ A}$
- Max $r_{DS(on)} = 6.2 \text{ m}\Omega \text{ at } V_{GS} = 4.5 \text{ V}, I_D = 16 \text{ A}$
- Advanced Package and Silicon combination for low r_{DS(on)} and high efficiency
- SyncFET Schottky Body Diode
- MSL1 robust package design
- 100% UIL tested
- RoHS Compliant

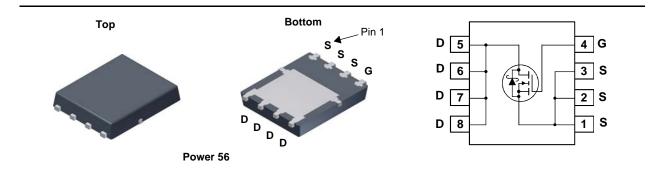


General Description

The FDMS0355S has been designed to minimize losses in power conversion application. Advancements in both silicon and package technologies have been combined to offer the lowest $r_{\text{DS}(\text{on})}$ while maintaining excellent switching performance.This device has the added benefit of an efficient monolithic Schottky body diode.

Applications

- Synchronous Rectifier for DC/DC Converters
- Notebook Vcore/GPU low side switch
- Networking Point of Load low side switch
- Telecom secondary side rectification



MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			30	V	
V _{GS}	Gate to Source Voltage		(Note 4)	±20	V	
	Drain Current -Continuous (Package limited)	$T_C = 25^{\circ}C$		22		
I _D	-Continuous (Silicon limited)	$T_C = 25^{\circ}C$		70	٨	
	-Continuous	$T_A = 25^{\circ}C$	(Note 1a)	18	A	
	-Pulsed			100		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	33	mJ	
D	Power Dissipation	T _C = 25°C		36	w	
P _D	Power Dissipation $T_A = 25^{\circ}C$ (Note 1a)		(Note 1a)	2.5	VV	
T _J , T _{STG}	Operating and Storage Junction Temperature Ra	ange		-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	3.4	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Note	la) 50	0/11

Package Marking and Ordering Information

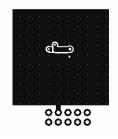
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS0355S	FDMS0355S	Power 56	13 "	12 mm	3000 units

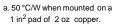
October 2014

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 1 mA, V _{GS} = 0 V	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	$I_D = 10$ mA, referenced to 25°C		18		mV/°C
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = 24 V, V_{GS} = 0 V$			500	μA
I _{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 1 \text{ mA}$	1.2	1.5	3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 10 \text{ mA}$, referenced to 25°C		-4		mV/°C
		V _{GS} = 10 V, I _D = 18 A		4.2	5.0	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 4.5 V, I_D = 16 A$		5.4	6.2	mΩ
		V_{GS} = 10 V, I _D = 18 A, T _J = 125°C		5.3	6.8	
9fs	Forward Transconductance	$V_{DS} = 5 V, I_{D} = 18 A$		92		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			1365	1815	pF
C _{oss}	Output Capacitance	V _{DS} = 15 V, V _{GS} = 0 V, f = 1MHz		550	730	pF
C _{rss}	Reverse Transfer Capacitance			70	105	pF
R _g	Gate Resistance			0.5	2.5	Ω
	Characteristics					
t _{d(on)}	Turn-On Delay Time			10	19	ns
t _r	Rise Time	V _{DD} = 15 V, I _D = 18 A,		2.3	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		25	40	ns
t _f	Fall Time			6	12	ns
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 10 V$		23	31	nC
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V V_{DD} = 15 V,$		11	16	nC
Q _{gs}	Gate to Source Charge	I _D = 18 A		3.3		nC
Q _{gd}	Gate to Drain "Miller" Charge			3.7		nC
Drain-Sou	urce Diode Characteristics					
V	Source-Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2 A$ (Note 2)		0.63	0.8	v
V _{SD}	Source Brain Blode Torward Vollage	V _{GS} = 0 V, I _S = 18 A (Note 2)		0.8	1.2	v
t _{rr}	Reverse Recovery Time	– I _F = 18 A, di/dt = 300 A/μs –		23	36	ns
Qrr	Reverse Recovery Charge	$F = 10 \text{ A}, \text{ al/at} = 300 \text{ A/}\mu\text{s}$		20	32	nC

Q_{rr} Notes

Notes: 1. R_{0,JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0,JC} is guaranteed by design while R_{0CA} is determined by the user's board design.

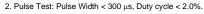






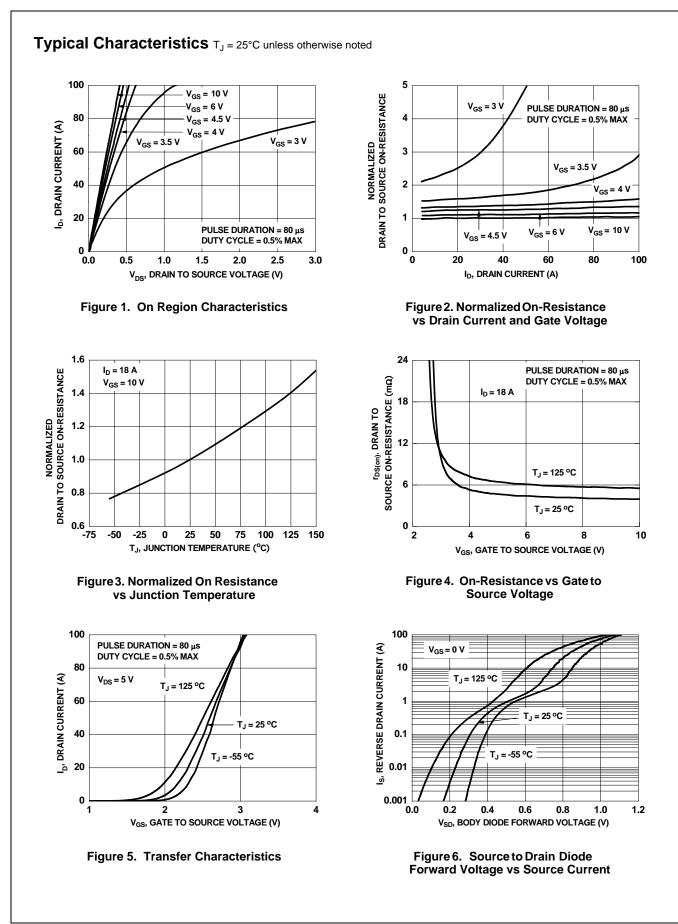
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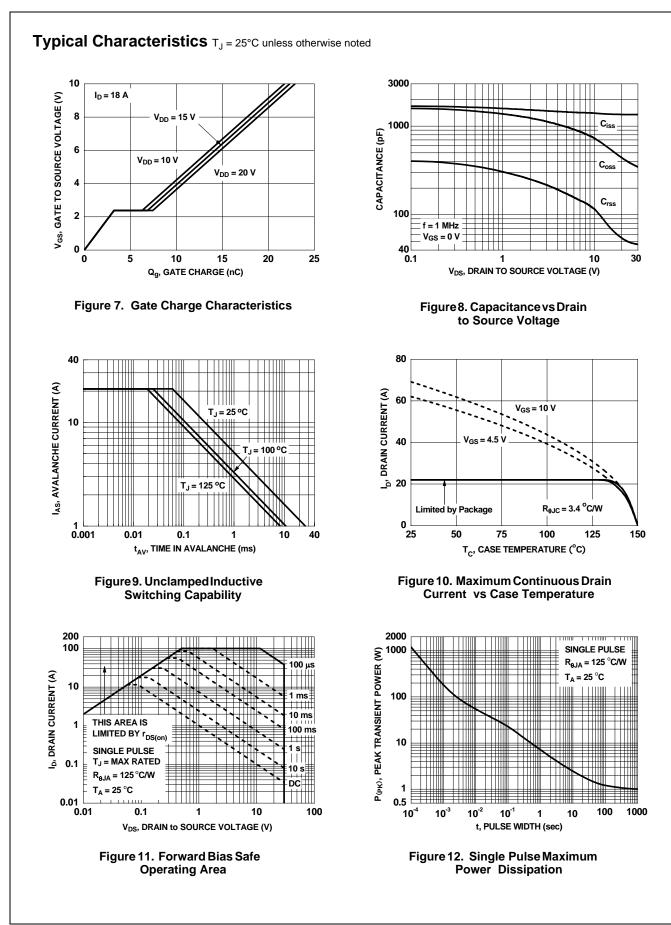
b. 125 °C/W when mounted on a minimum pad of 2 oz copper.



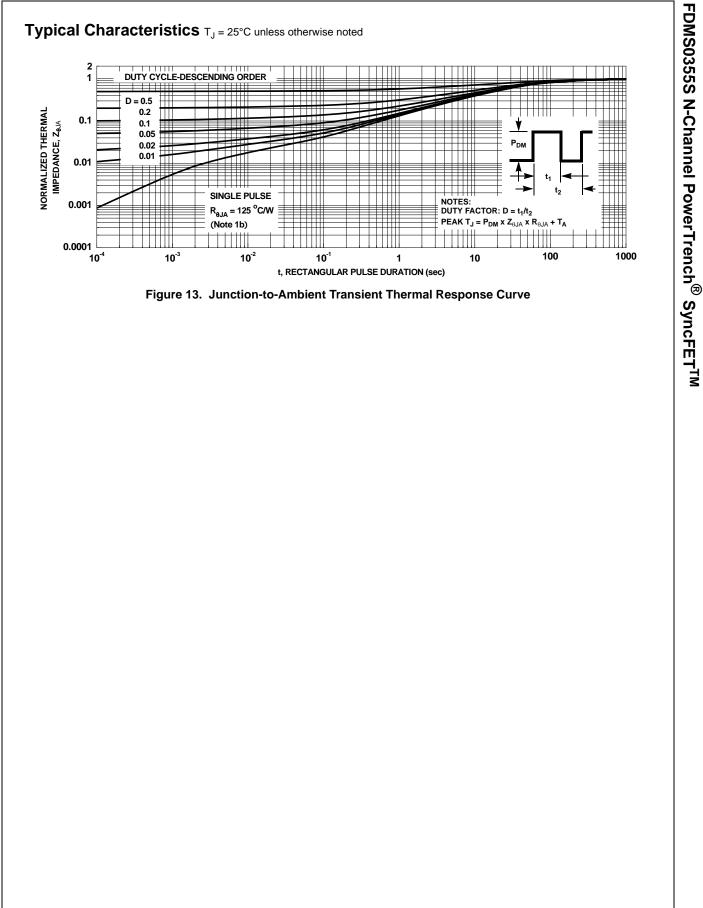
3. E_{AS} of 33 mJ is based on starting T_J = 25 °C, L = 0.3 mH, I_{AS} = 15 A, V_{DD} = 27 V, V_{GS} = 10 V.

4. As an N-ch device, the negative Vgs rating is for low duty cycle pulse occurrence only. No continuous rating is implied.





FDMS0355S N-Channel PowerTrench[®] SyncFETTM



Typical Characteristics (continued)

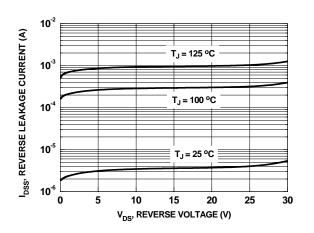
SyncFET Schottky body diode Characteristics

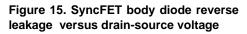
Fairchild's SyncFET process embeds a Schottky diode in parallel with PowerTrench MOSFET. This diode exhibits similar characteristics to a discrete external Schottky diode in parallel with a MOSFET. Figure 14 shows the reverse recovery characteristic of the FDMS8027S.

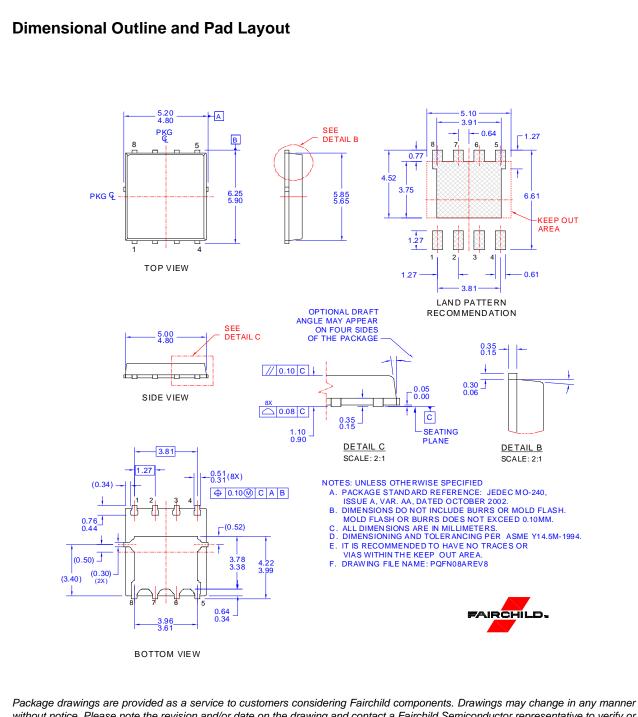
25 20 10 10 5 0 -5 10 20 30 40 50 TIME (ns)

Figure 14. FDMS8027S SyncFET body diode reverse recovery characteristic

Schottky barrier diodes exhibit significant leakage at high temperature and high reverse voltage. This will increase the power in the device.

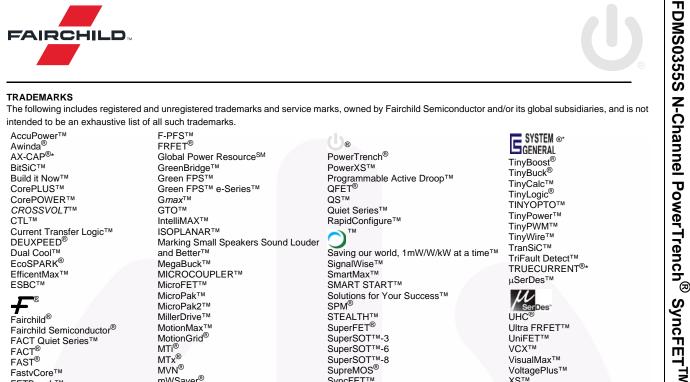






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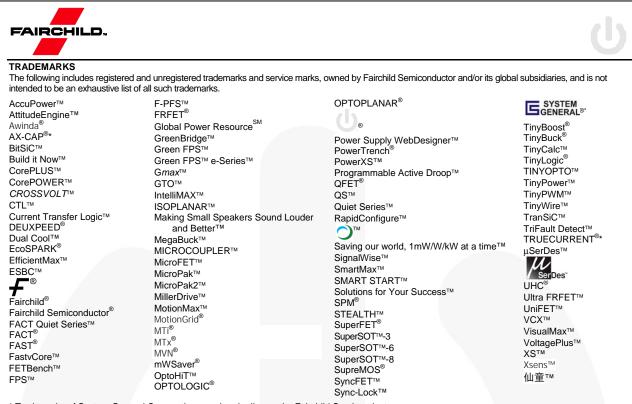
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FDMS0355S Rev.C1

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